



Hybrid Dual IGBT Driver

SKHI 22 A / B H4 (R)

Preliminary Data

Absolute Maximum Ratings			
Symbol	Conditions	Values	Units
V_S	Supply voltage prim.	18	V
V_{IH}	Input signal volt. (High) SKHI 22A H4 SKHI 22B H4	$V_S + 0,3$ 5 + 0,3	V
$I_{out,PEAK}$	Output peak current	8	A
$I_{out,AVmax}$	Output average current	40	mA
f_{max}	max. switching frequency	50	kHz
V_{CE}	Collector emitter voltage sense across the IGBT	1700	V
dv/dt	Rate of rise and fall of voltage secondary to primary side	50	kV/ μ s
V_{isolIO}	Isolation test voltage input - output (2 sec. AC)	4000	Vac
V_{isol12}	Isolation test voltage output 1 - output 2 (2 sec. AC)	1500	V
R_{Gonmin}	Minimum rating for R_{Gon}	3	Ω
$R_{Goffmin}$	Minimum rating for R_{Goff}	3	Ω
$Q_{out/pulse}$	Max. rating for output charge per pulse	4 ¹⁾	μ C
T_{op}	Operating temperature	- 40 ... + 85	°C
T_{stg}	Storage temperature	- 40 ... + 85	°C

Features

- Double driver for halfbridge IGBT modules
- SKHI 22A H4 is compatible to old SKHI 22 H4
- SKHI 22B H4 has additional functionality
- CMOS compatible inputs
- Short circuit protection by V_{CE} monitoring and switch off
- Drive interlock top / bottom
- Isolation by transformers
- Supply under voltage protection (13V)
- Error latch / output

Typical Applications

- Driver for IGBT modules in bridge circuits in choppers, inverter drives, UPS and welding inverters
- DC bus voltage up to 1200 V

¹⁾ see fig. 6

²⁾ At $R_{CE} = 36 \text{ k}\Omega$, $C_{CE} = 470 \text{ pF}$,
 $R_{VCE} = 1 \text{ k}\Omega$

Characteristics $T_a = 25 \text{ }^\circ\text{C}$, unless otherwise specified				
Symbol	Conditions	min.	typ.	max.
V_S	Supply voltage primary side	14,4	15	15,6
I_{SO}	Supply current primary side (no load)		80	
	Supply current primary side (max.)			290
V_i	Input signal voltage SKHI 22A H4 on/off SKHI 22B H4 on/off		15 / 0 5 / 0	
V_{IT+}	Input threshold volt. (High) SKHI 22A H4 SKHI 22B H4	10,9	11,7	12,5
V_{IT-}	Input threshold volt. (Low) SKHI 22A H4 SKHI 22B H4	4,7	5,5	6,5
R_{in}	Input resistance SKHI 22A H4 SKHI 22B H4		1,5	2,0
$V_{G(on)}$	Turn on gate voltage output		+ 15	
$V_{G(off)}$	Turn off gate voltage output		- 7	
R_{GE}	Internal gate-emitter resistance		22	
f_{ASIC}	Asic system switching frequency		8	
$t_{d(on)IO}$	Input-output turn-on propagation time	0,85	1	1,15
$t_{d(off)IO}$	Input-output turn-off propagation time	0,85	1	1,15
$t_{d(err)}$	Error input-output propagation time		0,6	
$t_{pERRRESET}$	Error reset time		9	
t_{TD}	Top-Bot Interl. Dead Time SKHI 22A H4 SKHI 22B H4	3,3		4,3
		no interlock		4,3
V_{CEsat}	Reference voltage for V_{CE} -monitoring		5 ²⁾	10
C_{ps}	Coupling capacitance primary secondary		12	
$MTBF$	Mean Time Between Failure $T_a = 40^\circ\text{C}$		2,0	10^6 h
w	weight		45	g

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